

Complementary N & P-Channel Power MOSFET

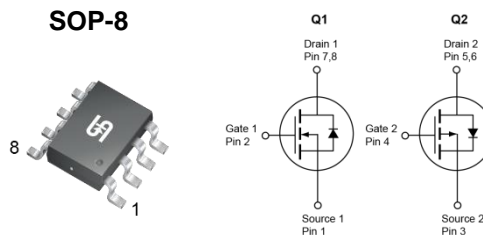
FEATURES

- Low gate charge for fast power switching
- 100% UIS and R_{θ} tested
- Compliant to RoHS directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

APPLICATIONS

- Building technologies
- DC Fan
- Motor drives

KEY PERFORMANCE PARAMETERS			
PARAMETER	TYPE	VALUE	UNIT
V_{DS}	Q1	60	V
	Q2	-60	
$R_{DS(on)}$ (max)	Q1	$V_{GS} = 10V$	103
		$V_{GS} = 4.5V$	122
	Q2	$V_{GS} = -10V$	180
		$V_{GS} = -4.5V$	220
Q_g	Q1	4.4	nC
	Q2	4.6	



Note: MSL 1 (Moisture Sensitivity Level) per J-STD-020

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^{\circ}C$ unless otherwise noted)				
PARAMETER	SYMBOL	Q1	Q2	UNIT
Drain-Source Voltage	V_{DS}	60	-60	V
Gate-Source Voltage	V_{GS}	± 20	± 20	V
Continuous Drain Current	I_D	$T_C = 25^{\circ}C$	5	-4
		$T_A = 25^{\circ}C$	2.5	-2
Pulsed Drain Current (Note 1)	I_{DM}	20	-16	A
Single Pulse Avalanche Current (Note 2)	I_{AS}	6.8	-7	A
Single Pulse Avalanche Energy (Note 2)	E_{AS}	6.9	7.4	mJ
Total Power Dissipation	P_D	$T_C = 25^{\circ}C$	5.7	5.7
		$T_C = 125^{\circ}C$	1.1	1.1
Total Power Dissipation	P_D	$T_A = 25^{\circ}C$	1.4	1.4
		$T_A = 125^{\circ}C$	0.3	0.3
Operating Junction and Storage Temperature Range	T_J, T_{STG}	- 55 to +150		$^{\circ}C$

THERMAL PERFORMANCE			
PARAMETER	SYMBOL	MAXIMUM	UNIT
Thermal Resistance – Junction to Case	$R_{\theta JC}$	22	$^{\circ}C/W$
Thermal Resistance – Junction to Ambient	$R_{\theta JA}$	88	

Thermal Performance Note: $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistances. The case-thermal reference is defined at the solder mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design while $R_{\theta CA}$ is determined by the user's board design. The $R_{\theta JA}$ limit presented here is based on mounting on a 1 in² pad of 2 oz copper.

ELECTRICAL SPECIFICATIONS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

PARAMETER	CONDITIONS	SYMBOL	TYPE	MIN	TYP	MAX	UNIT		
Static									
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250\mu A$	BV_{DSS}	Q1	60	--	--	V		
	$V_{GS} = 0V, I_D = -250\mu A$		Q2	-60	--	--			
Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250\mu A$	$V_{GS(TH)}$	Q1	1.2	1.8	2.5	V		
	$V_{GS} = V_{DS}, I_D = -250\mu A$		Q2	-1	-1.5	-2.5			
Gate-Source Leakage Current	$V_{GS} = \pm 20V, V_{DS} = 0V$	I_{GSS}	Q1	--	--	± 100	nA		
	$V_{GS} = \pm 20V, V_{DS} = 0V$		Q2	--	--	± 100	nA		
Drain-Source Leakage Current	$V_{GS} = 0V, V_{DS} = 60V$	I_{DSS}	Q1	--	--	1	μA		
	$V_{GS} = 0V, V_{DS} = -60V$		Q2	--	--	-1			
Drain-Source On-State Resistance <small>(Note 3)</small>	$V_{GS} = 10V, I_D = 2.5A$	$R_{DS(on)}$	Q1	--	74	103	m Ω		
	$V_{GS} = 4.5V, I_D = 2.3A$			--	86	122			
	$V_{GS} = -10V, I_D = -2A$		Q2	--	135	180			
	$V_{GS} = -4.5V, I_D = -1.7A$			--	170	220			
Forward Transconductance <small>(Note 3)</small>	$V_{DS} = 10V, I_D = 2.5A$	g_{fs}	Q1	--	10	--	S		
	$V_{DS} = -10V, I_D = -2A$		Q2	--	5	--			
Dynamic <small>(Note 4)</small>									
Total Gate Charge	Q1 $V_{DS} = 30V, I_D = 2.5A$ Q2 $V_{DS} = -30V, I_D = -2A$	$Q_{g(VGS=10V)}$	Q1	--	9.4	--	nC		
Total Gate Charge			Q2	--	9	--			
		Gate-Source Charge	$Q_{g(VGS=4.5V)}$	Q1	--	4.4		--	
Q2				--	4.6	--			
Gate-Drain Charge		Q_{gs}	Q1	--	1.8	--			
			Q2	--	1.2	--			
Input Capacitance		Q1 $V_{GS} = 0V, V_{DS} = 30V$	C_{iss}	Q1	--	527		--	pF
				Q2	--	436		--	
Output Capacitance	f = 1.0MHz Q2	C_{oss}	Q1	--	31	--			
			Q2	--	32	--			
Reverse Transfer Capacitance	$V_{GS} = 0V, V_{DS} = -30V$ f = 1.0MHz	C_{rss}	Q1	--	4	--			
			Q2	--	11	--			
Gate Resistance	f = 1.0MHz	R_g	Q1	0.5	1.8	3.6	Ω		
			Q2	5	17	34			
Switching <small>(Note 4)</small>									
Turn-On Delay Time	Q1 $V_{GS} = 10V, V_{DS} = 30V,$ $I_D = 2.5A, R_G = 2\Omega$	$t_{d(on)}$	Q1	--	5	--	ns		
			Q2	--	3.4	--			
Turn-On Rise Time	Q2 $V_{GS} = -10V, V_{DS} = -30V,$ $I_D = -2A, R_G = 2\Omega$	t_r	Q1	--	21	--			
			Q2	--	21	--			
Turn-Off Delay Time		$t_{d(off)}$	Q1	--	10	--			
			Q2	--	21	--			
Turn-Off Fall Time		t_f	Q1	--	17	--			
			Q2	--	26	--			

ELECTRICAL SPECIFICATIONS ($T_A = 25^\circ\text{C}$ unless otherwise noted)							
PARAMETER	CONDITIONS	SYMBOL	TYPE	MIN	TYP	MAX	UNIT
Source-Drain Diode							
Forward Voltage (Note 3)	$V_{GS} = 0V, I_S = 2.5A$	V_{SD}	Q1	--	--	1	V
	$V_{GS} = 0V, I_S = -2A$		Q2	--	--	-1	
Reverse Recovery Time	Q1 $I_S = 2.5A, di/dt = 100A/\mu s$	t_{rr}	Q1	--	14	--	ns
			Q2	--	11	--	
Reverse Recovery Charge	Q2 $I_S = -2A, di/dt = 100A/\mu s$	Q_{rr}	Q1	--	10	--	nC
			Q2	--	6	--	

Notes:

- Current limited by package.
- Q1 : $L = 0.3mH, V_{GS} = 10V, V_{DD} = 30V, R_G = 25\Omega, I_{AS} = 6.8A$, Starting $T_J = 25^\circ\text{C}$
 Q2 : $L = 0.3mH, V_{GS} = -10V, V_{DD} = -30V, R_G = 25\Omega, I_{AS} = -7A$, Starting $T_J = 25^\circ\text{C}$
- Pulse test: Pulse Width $\leq 300\mu s$, duty cycle $\leq 2\%$.
- Switching time is essentially independent of operating temperature.

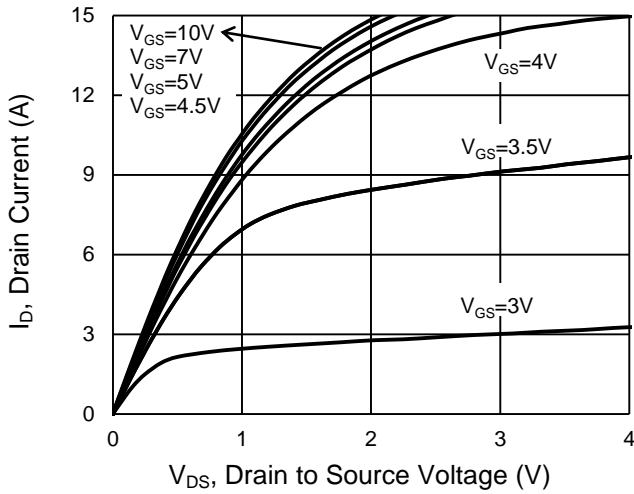
ORDERING INFORMATION

ORDERING CODE	PACKAGE	PACKING
TSM8588CS RLG	SOP-8	2,500pcs / 13" Reel

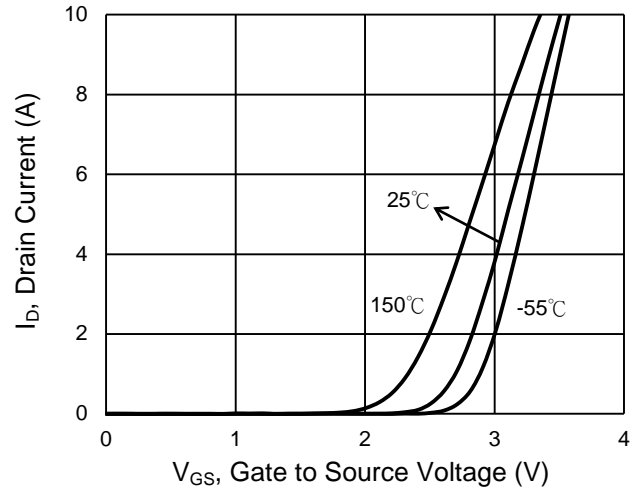
CHARACTERISTICS CURVES (Q1 N-Channel)

($T_A = 25^\circ\text{C}$ unless otherwise noted)

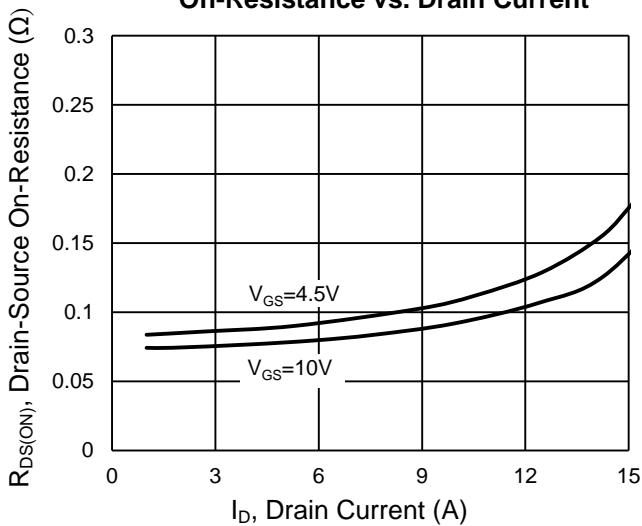
Output Characteristics



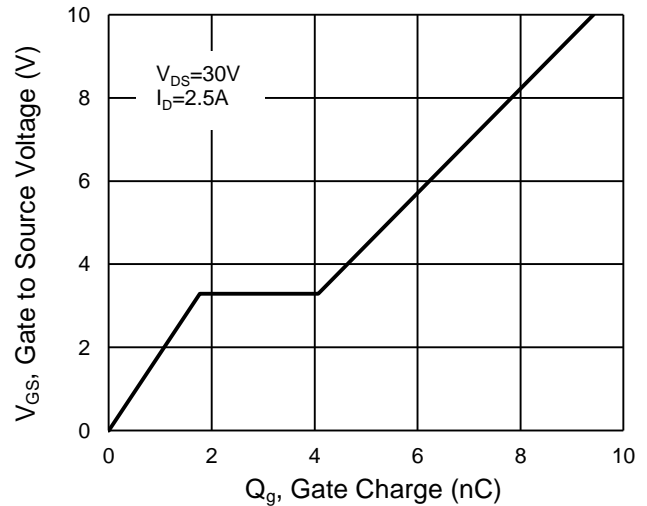
Transfer Characteristics



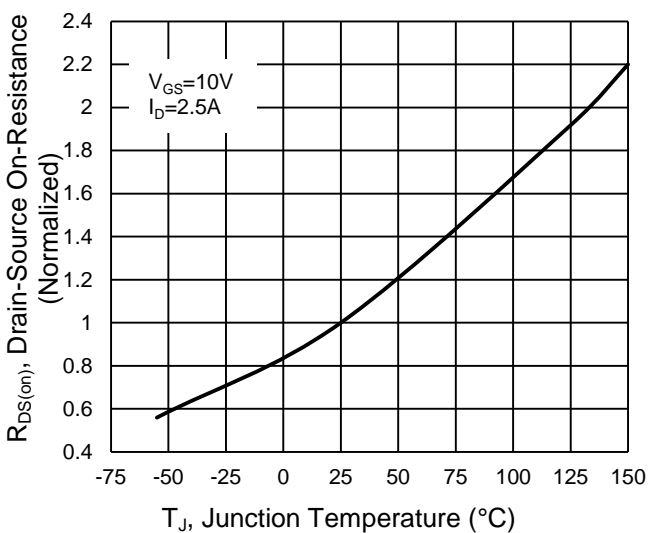
On-Resistance vs. Drain Current



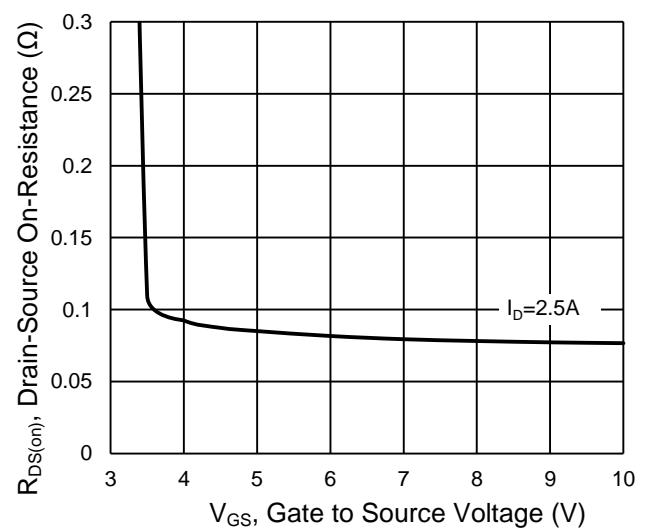
Gate-Source Voltage vs. Gate Charge



On-Resistance vs. Junction Temperature

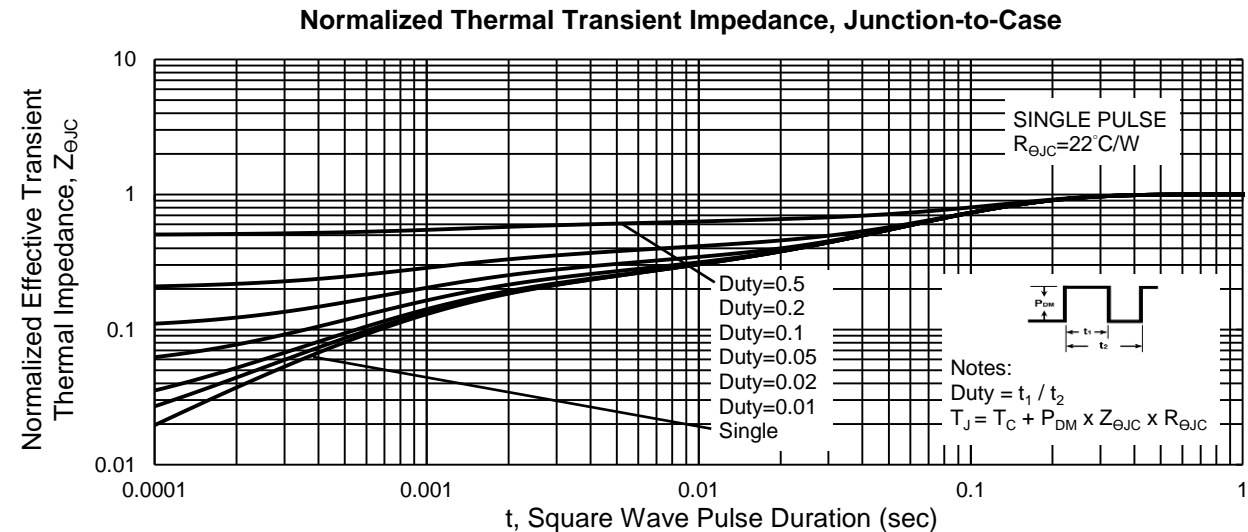
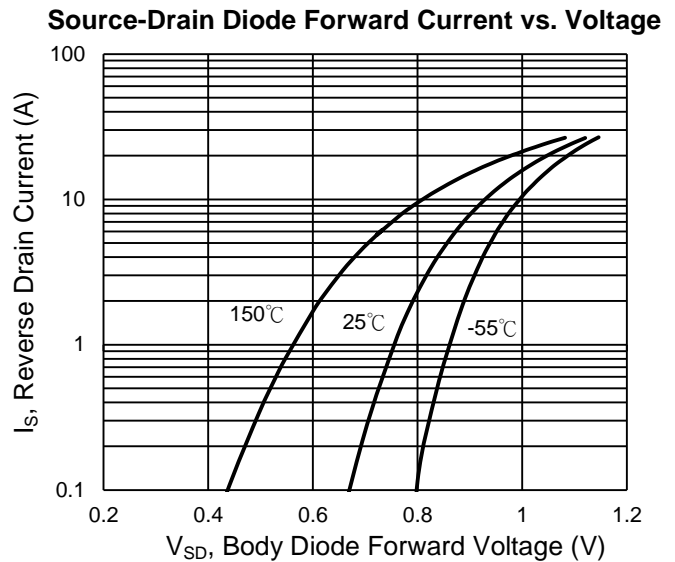
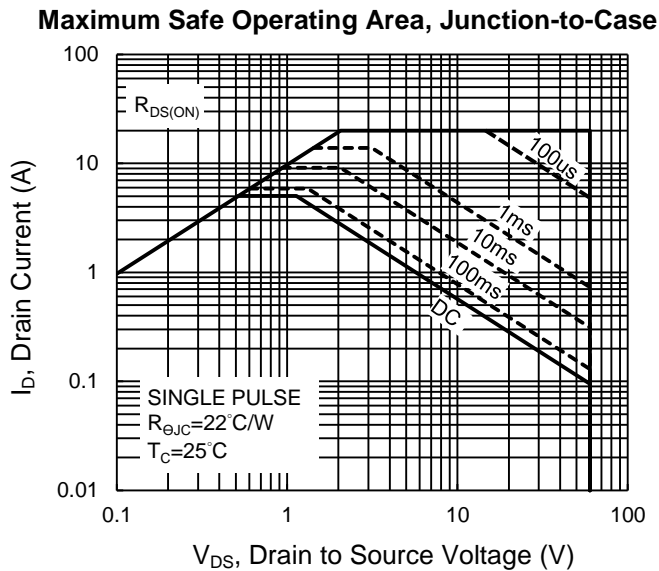
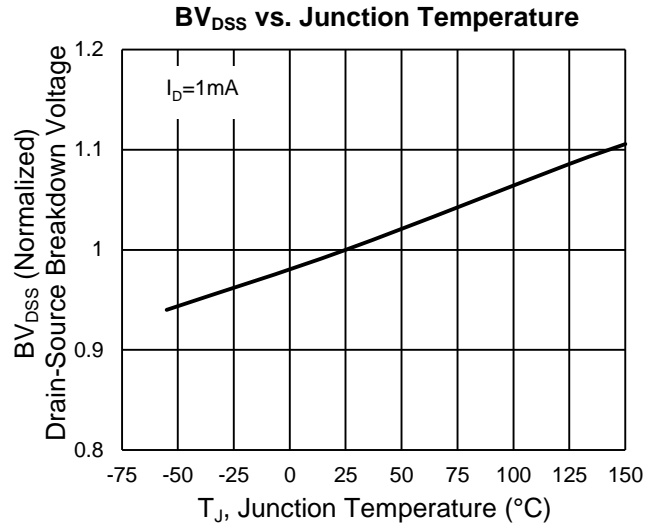
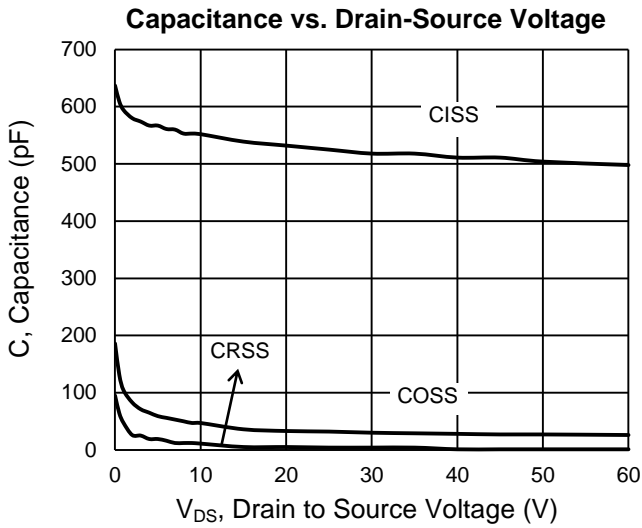


On-Resistance vs. Gate-Source Voltage



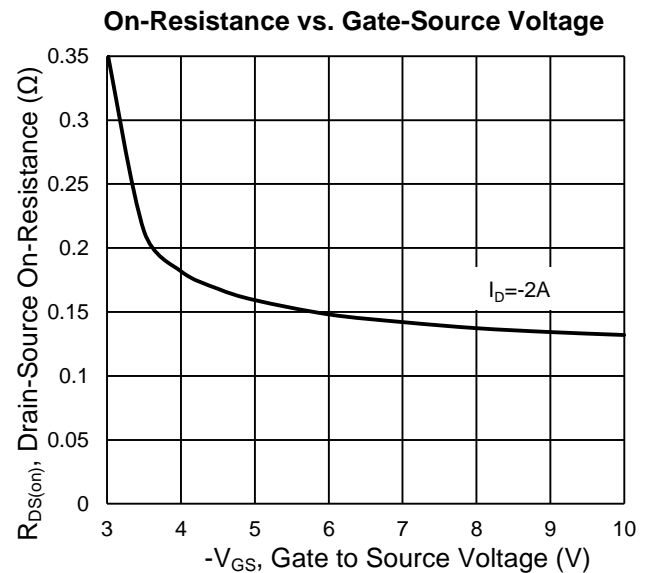
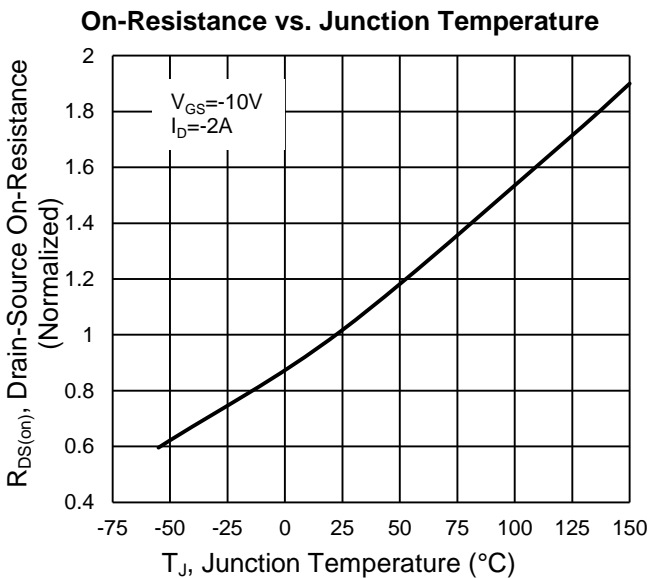
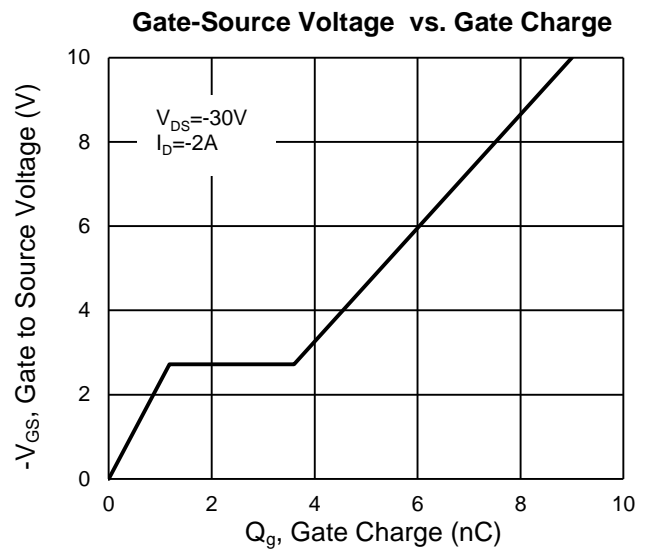
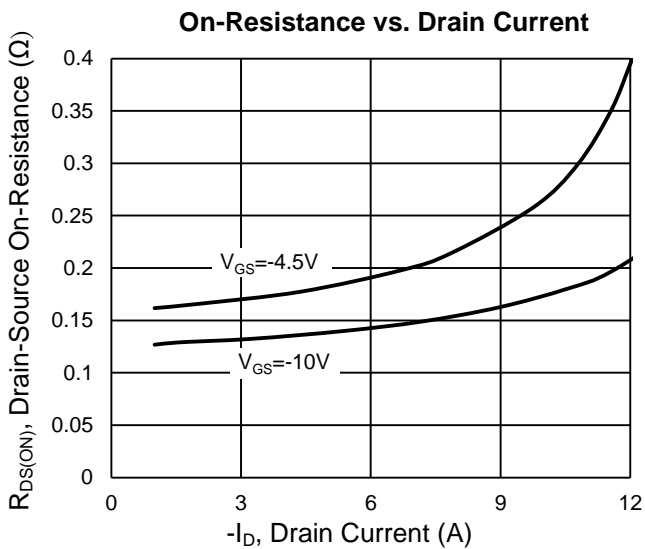
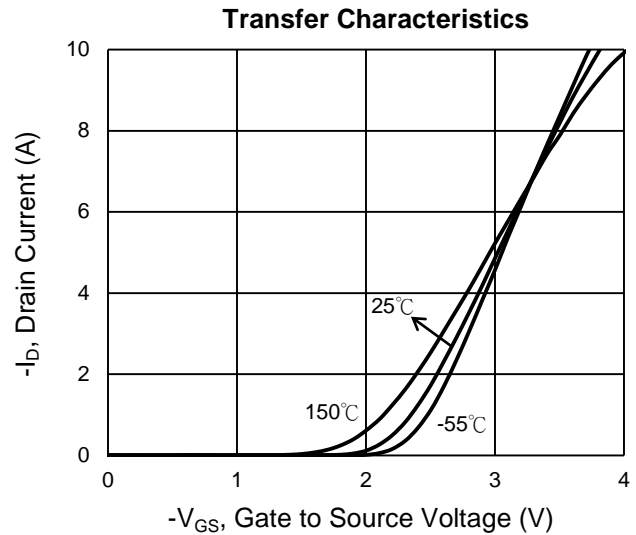
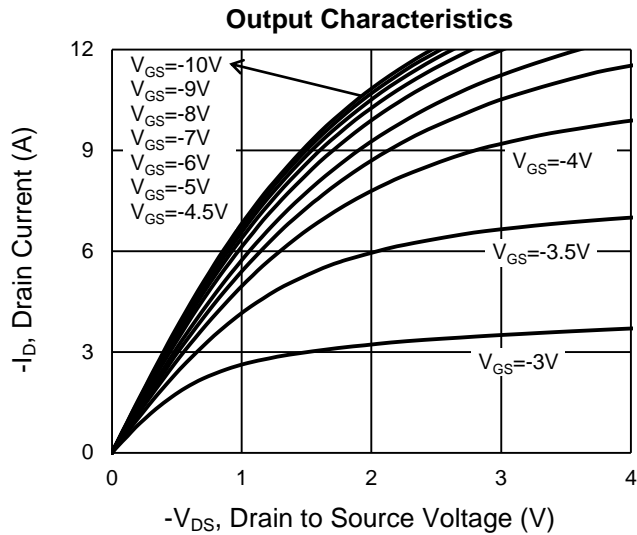
CHARACTERISTICS CURVES

($T_A = 25^\circ\text{C}$ unless otherwise noted)



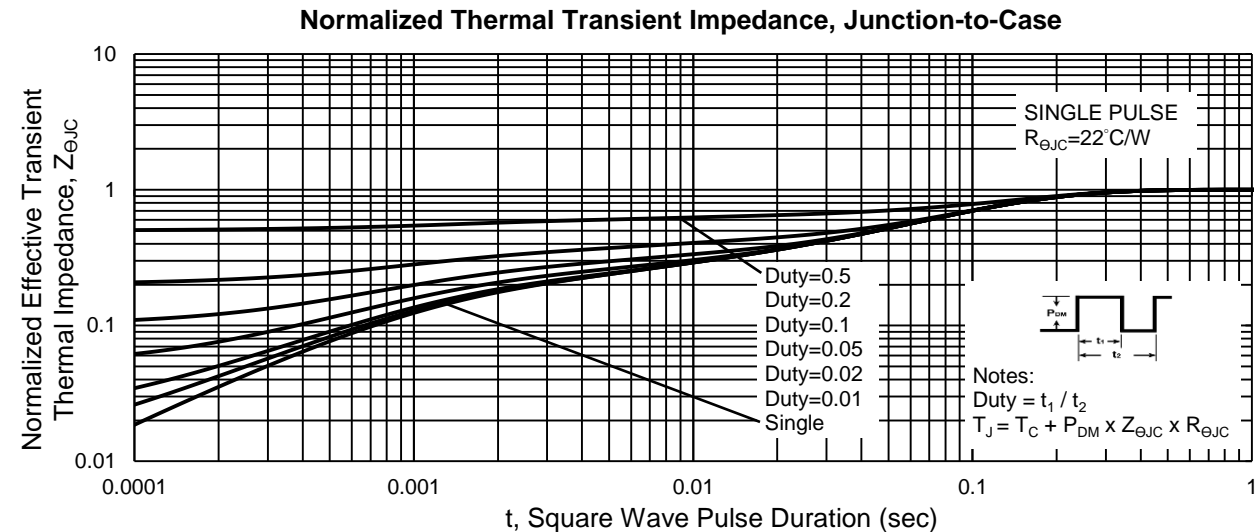
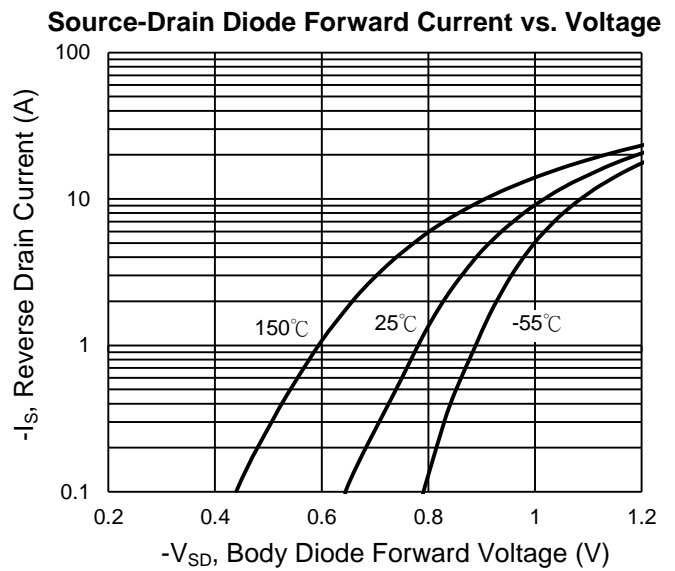
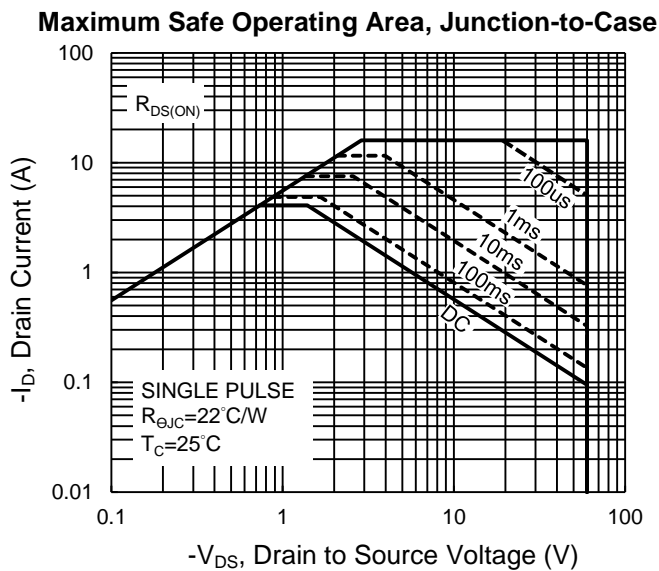
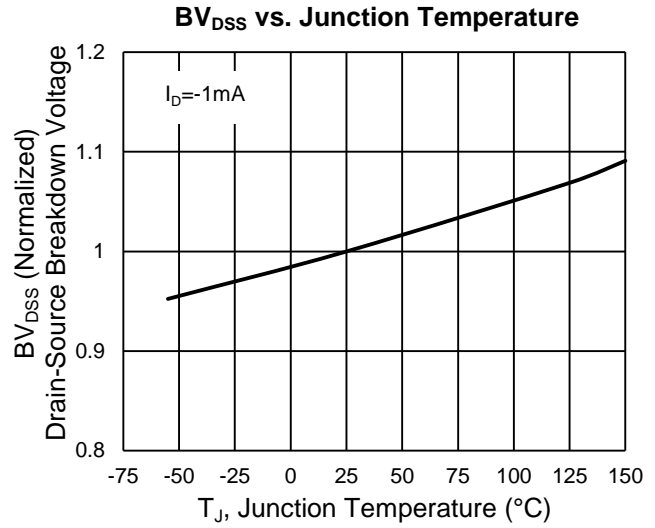
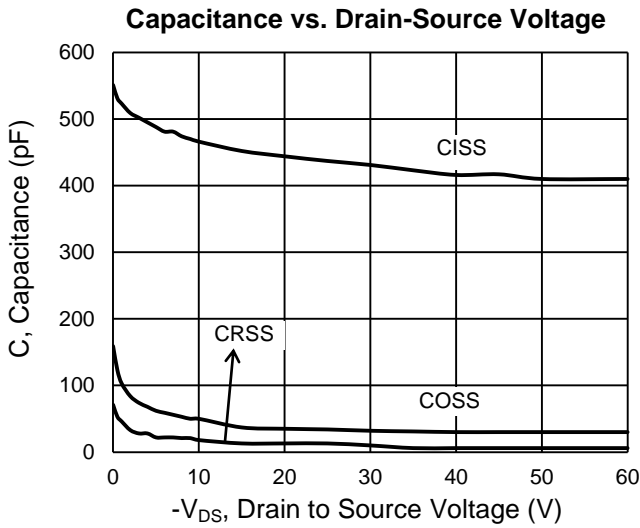
CHARACTERISTICS CURVES (Q2 P-Channel)

($T_A = 25^\circ\text{C}$ unless otherwise noted)



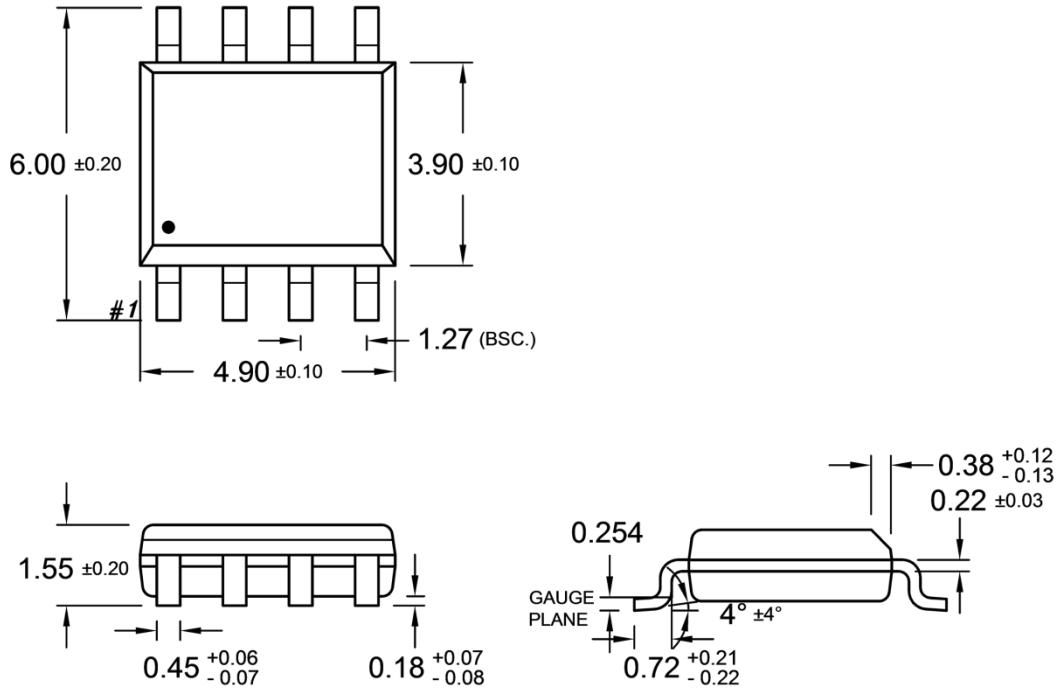
CHARACTERISTICS CURVES

($T_A = 25^\circ\text{C}$ unless otherwise noted)

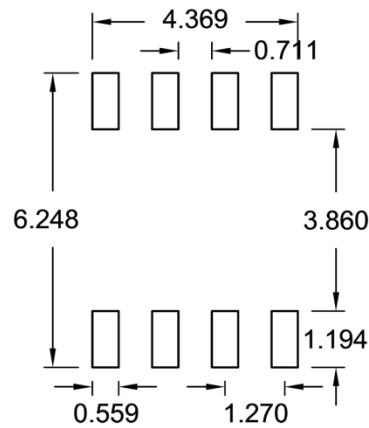


PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)

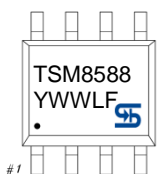
SOP-8



SUGGESTED PAD LAYOUT (Unit: Millimeters)



MARKING DIAGRAM



- Y** = Year Code
- WW** = Week Code (01~52)
- L** = Lot Code (1~9,A~Z)
- F** = Factory Code

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